EMX1DXV6T1G, EMX1DXV6T5G

Dual NPN General Purpose Amplifier Transistor

This NPN transistor is designed for general purpose amplifier applications. This device is housed in the SOT-563 package which is designed for low power surface mount applications, where board space is at a premium.

Features

- Reduces Board Space
- High h_{FE}, 210–460 (Typical)
- Low V_{CE(sat)}, < 0.5 V
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{(BR)CBO}	60	Vdc
Collector-Emitter Voltage	V _{(BR)CEO}	50	Vdc
Emitter-Base Voltage	$V_{(BR)EBO}$	7.0	Vdc
Collector Current – Continuous	I _C	100	mAdc

THERMAL CHARACTERISTICS

Characteristic (One Junction Heated)	Symbol	Max	Unit
Total Device Dissipation T _A = 25°C Derate above 25°C	P _D	357 (Note 1) 2.9 (Note 1)	mW mW/°C
Thermal Resistance – Junction-to-Ambient	$R_{\theta JA}$	350 (Note 1)	°C/W
Characteristic (Both Junctions Heated)	Symbol	Max	Unit
Total Device Dissipation T _A = 25°C Derate above 25°C	P _D	500 (Note 1) 4.0 (Note 1)	mW mW/°C
Thermal Resistance – Junction-to-Ambient	$R_{\theta JA}$	250 (Note 1)	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

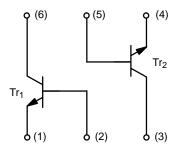
1. FR-4 @ Minimum Pad



ON Semiconductor®

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DUAL NPN GENERAL PURPOSE AMPLIFIER TRANSISTORS SURFACE MOUNT





SOT-563 CASE 463A STYLE 1

MARKING DIAGRAM



3X = Specific Device Code M = Month Code

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

EMX1DXV6T1G, EMX1DXV6T5G

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

Characteristic	Symbol	Min	Тур	Max	Unit
Collector-Base Breakdown Voltage ($I_C = 50 \mu Adc$, $I_E = 0$)	V _{(BR)CBO}	60	_	-	Vdc
Collector-Emitter Breakdown Voltage $(I_C = 1.0 \text{ mAdc}, I_B = 0)$	V _{(BR)CEO}	50	_	-	Vdc
Emitter-Base Breakdown Voltage $(I_E = 50 \mu Adc, I_E = 0)$	V _{(BR)EBO}	7.0	_	-	Vdc
Collector-Base Cutoff Current $(V_{CB} = 60 \text{ Vdc}, I_E = 0)$	Ісво	-	_	0.5	μΑ
Emitter-Base Cutoff Current $(V_{EB} = 7.0 \text{ Vdc}, I_{B} = 0)$	I _{EBO}	-	_	0.5	μΑ
Collector-Emitter Saturation Voltage (Note 2) $(I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc})$	V _{CE(sat)}	-	_	0.4	Vdc
DC Current Gain (Note 3) (V _{CE} = 6.0 Vdc, I _C = 1.0 mAdc)	h _{FE}	120	_	560	-
Transition Frequency ($V_{CE} = 12 \text{ Vdc}, I_{C} = 2.0 \text{ mAdc}, f = 30 \text{ MHz}$)	f _T	-	180	_	MHz
Output Capacitance (V _{CB} = 12 Vdc, I _C = 0 Adc, f = 1 MHz)	СОВ	-	2.0	-	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Device mounted on a FR-4 glass epoxy printed circuit board using the minimum recommended footprint.

ORDERING INFORMATION

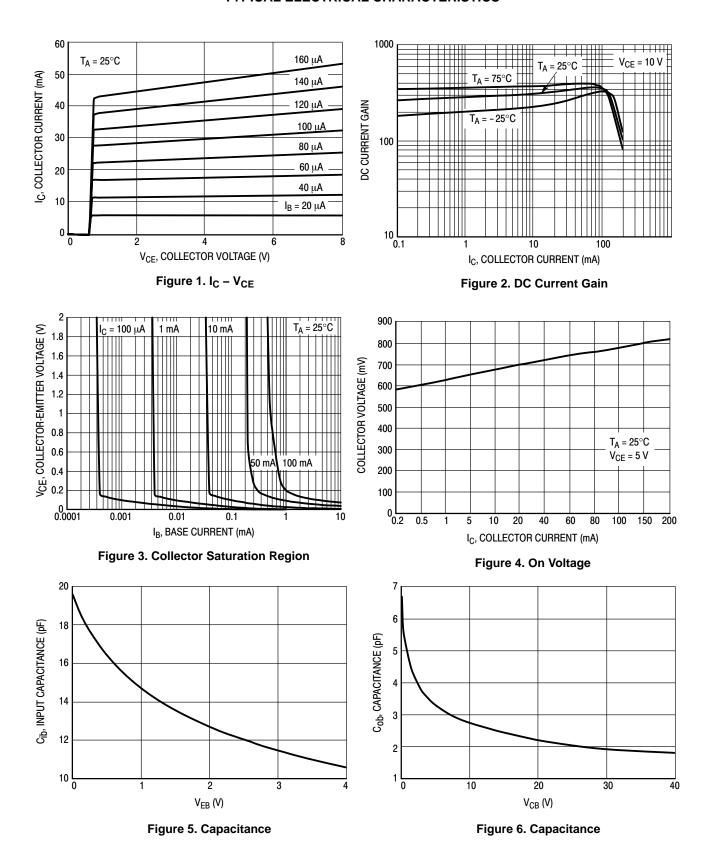
Device	Package	Shipping [†]
EMX1DXV6T1G	SOT-563 (Pb-Free)	4000 Units / Tape & Reel
EMX1DXV6T5G	SOT-563 (Pb-Free)	8000 Units / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{3.} Pulse Test: Pulse Width $\leq 300 \,\mu\text{s}$, D.C. $\leq 2\%$.

EMX1DXV6T1G, EMX1DXV6T5G

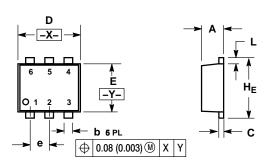
TYPICAL ELECTRICAL CHARACTERISTICS



EMX1DXV6T1G, EMX1DXV6T5G

PACKAGE DIMENSIONS

SOT-563, 6 LEAD CASE 463A ISSUE G



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.50	0.55	0.60	0.020	0.021	0.023
b	0.17	0.22	0.27	0.007	0.009	0.011
С	0.08	0.12	0.18	0.003	0.005	0.007
D	1.50	1.60	1.70	0.059	0.062	0.066
Е	1.10	1.20	1.30	0.043	0.047	0.051
е		0.5 BSC		0.02 BSC		
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	1.50	1.60	1.70	0.059	0.062	0.066

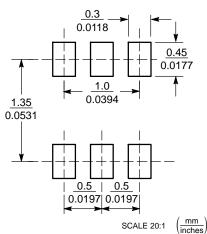
STYLE 1: PIN 1. EMITTER 1

2. BASE 1 3. COLLECTOR 2

EMITTER 2 BASE 2

COLLECTOR 1

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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